

PHOTOCOUPLER

PS9552,PS9552L1,PS9552L2,PS9552L3

2.5 A OUTPUT CURRENT, HIGH CMR IGBT GATE DRIVE PHOTOCOUPLER 8-PIN DIP PHOTOCOUPLER

-NEPOC Series-

DESCRIPTION

The PS9552, PS9552L1, PS9552L2 and PS9552L3 are optically coupled isolators containing a GaAlAs LED on the input side and a photo diode, a signal processing circuit and a power output transistor on the output side on one chip.

The PS9552 Series is designed specifically for high common mode transient immunity (CMR), high output current and high switching speed.

The PS9552 Series is suitable for driving IGBTs and MOS FETs.

The PS9552 Series is in a plastic DIP (Dual In-line Package).

The PS9552L1 is lead bending type for long creepage distance.

The PS9552L2 is lead bending type for long creepage distance (Gull-wing) for surface mount.

The PS9552L3 is lead bending type (Gull-wing) for surface mounting.

FEATURES



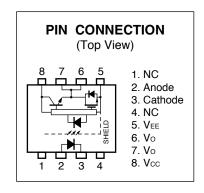
- Long creepage distance (8 mm MIN.: PS9552L1, PS9552L2)
- Large peak output current (2.5 A MAX., 2.0 A MIN.)
- High speed switching (tplh/tphl = 0.5 μ s MAX.)
- UVLO (Under Voltage Lock Out) protection with hysteresis
- High common mode transient immunity (CMH, CML = ±15 kV/μs MIN.)
- Ordering number of tape product: PS9552L2-E3: 1 000 pcs/reel

: PS9552L3-E3: 1 000 pcs/reel

- · Safety standards
 - UL approved: File No. E72422
 - · CSA approved: No. CA 101391
 - BSI approved: No. 8937, 8938
 - SEMKO approved: No. 615433
 - NEMKO approved: No. P06207243
 - · DEMKO approved: No. 314091
 - · FIMKO approved: No. FI 22827
 - DIN EN60747-5-2 (VDE0884 Part2) approved (Option)

APPLICATIONS

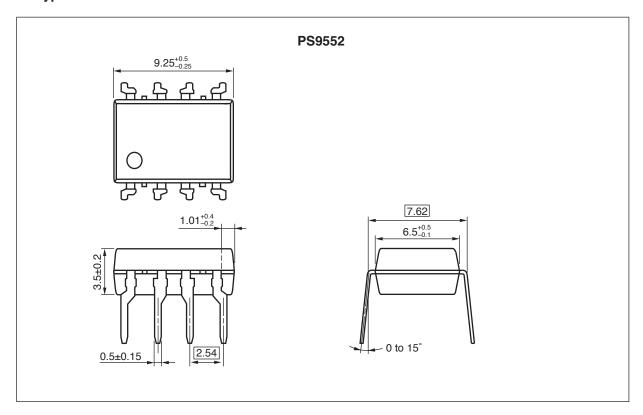
- · IGBT, Power MOS FET Gate Driver
- · Industrial inverter
- · IH (Induction Heating)



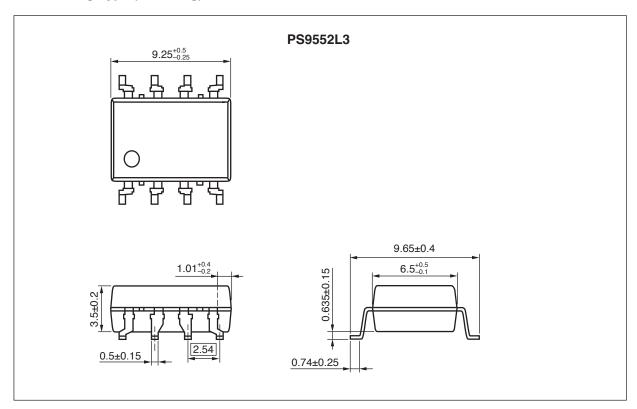
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PACKAGE DIMENSIONS (UNIT: mm)

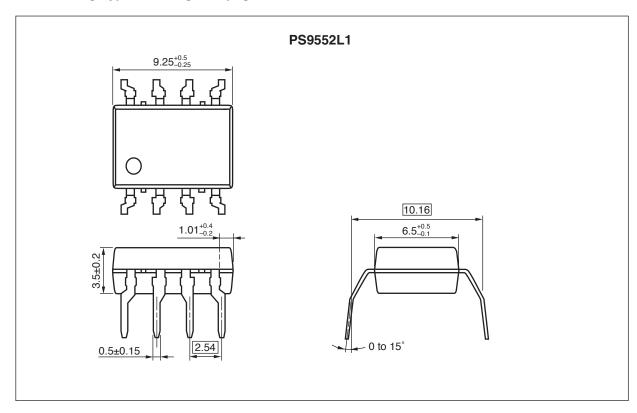
DIP Type



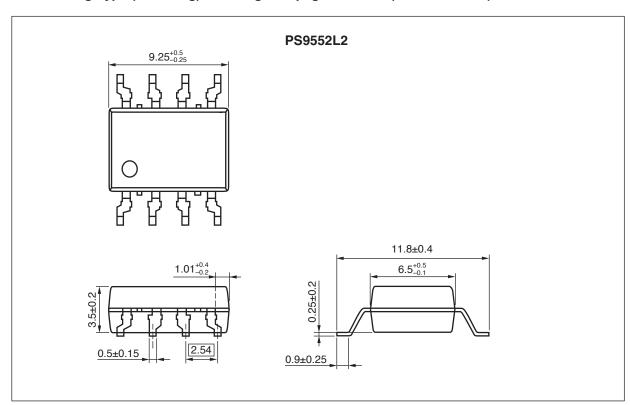
Lead Bending Type (Gull-wing) For Surface Mount



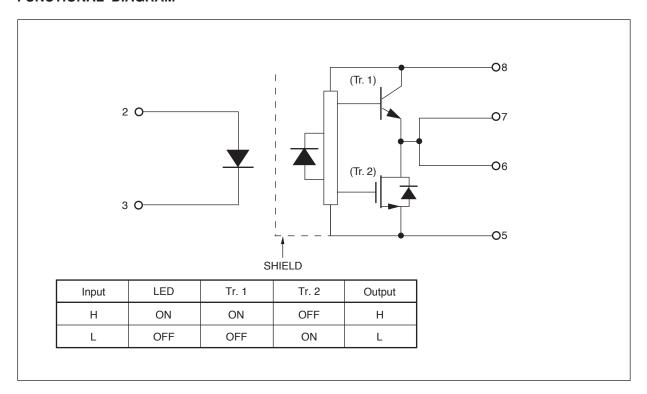
Lead Bending Type For Long Creepage Distance



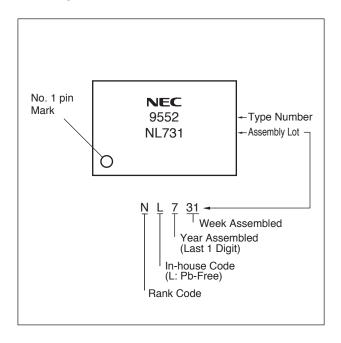
Lead Bending Type (Gull-wing) For Long Creepage Distance (Surface Mount)



<R> FUNCTIONAL DIAGRAM



<R> MARKING EXAMPLE



PHOTOCOUPLER CONSTRUCTION

Parameter	PS9552, PS9552L3	PS9552L1, PS9552L2
Air Distance (MIN.)	7 mm	8 mm
Outer Creepage Distance (MIN.)	7 mm	8 mm
Isolation Distance (MIN.)	0.4 mm	0.4 mm

<R> ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application Part Number*1
PS9552	PS9552-AX	Pb-Free	Magazine case 50 pcs	Standard products	PS9552
PS9552L1	PS9552L1-AX	(Ni/Pd/Au)		(UL, CSA, BSI,	PS9552L1
PS9552L2	PS9552L2-AX			SEMKO, NEMKO,	PS9552L2
PS9552L3	PS9552L3-AX			DEMKO, FIMKO	PS9552L3
PS9552L2-E3	PS9552L2-E3-AX		Embossed Tape 1 000 pcs/reel	approved)	PS9552L2
PS9552L3-E3	PS9552L3-E3-AX				PS9552L3
PS9552-V	PS9552-V-AX		Magazine case 50 pcs	DIN EN60747-5-2	PS9552
PS9552L1-V	PS9552L1-V-AX			(VDE0884 Part2)	PS9552L1
PS9552L2-V	PS9552L2-V-AX			Approved (Option)	PS9552L2
PS9552L3-V	PS9552L3-V-AX				PS9552L3
PS9552L2-V-E3	PS9552L2-V-E3-AX		Embossed Tape 1 000 pcs/reel		PS9552L2
PS9552L3-V-E3	PS9552L3-V-E3-AX				PS9552L3

^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C, unless otherwise specified)

	Parameter	Symbol	Ratings	Unit
Diode	Forward Current	lF	25	mA
	Peak Transient Forward Current (Pulse Width < 1 μ s)	IF (TRAN)	1.0	А
	Reverse Voltage	VR	5	V
Detector	High Level Peak Output Current 1	Іон (РЕАК)	2.5	Α
	Low Level Peak Output Current 1	OL (PEAK)	2.5	А
	Supply Voltage	(Vcc - Vee)	0 to 35	V
	Output Voltage	Vo	0 to Vcc	V
	Power Dissipation '2	Pc	250	mW
Isolation	Voltage ^{*3}	BV	5 000	Vr.m.s.
Total Pov	ver Dissipation *4	Рт	300	mW
Operating	g Frequency ^{⁺₅}	f	50	kHz
Operating	g Ambient Temperature	Та	-40 to +100	°C
Storage -	Temperature	T _{stg}	-55 to +125	°C

- *1 Maximum pulse width = 10 μ s, Maximum duty cycle = 0.2%
- *2 Reduced to 4.8 mW/°C at T_A = 70°C or more.
- *3 AC voltage for 1 minute at T_A = 25°C, RH = 60% between input and output. Pins 1-4 shorted together, 5-8 shorted together.
- *4 Reduced to 5.4 mW/ $^{\circ}$ C at T_A = 70 $^{\circ}$ C or more.
- *5 IOH (PEAK) ≤ 2.0 A ($\leq 0.3~\mu$ S), IOL (PEAK) ≤ 2.0 A ($\leq 0.3~\mu$ S)

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage	(Vcc - Vee)	15		30	V
Forward Current (ON)	IF (ON)	7	10	16	mA
Forward Voltage (OFF)	VF (OFF)	-2		0.8	V
Operating Ambient Temperature	TA	-40		100	°C

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ELECTRICAL CHARACTERISTICS (Ta = -40 to +100°C, Vcc = 15 to 30 V, IF (ON) = 7 to 16 mA, $V_{F(OFF)} = -2 \text{ to } 0.8 \text{ V}, V_{EE} = GND, unless otherwise specified}$

	Parameter	Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit
Diode	Forward Voltage	VF	I _F = 10 mA, T _A = 25°C	1.3	1.65	2.1	V
	Input Capacitance	Cin	f = 1 MHz, V _F = 0 V, T _A = 25°C		60		pF
Detector	High Level Output Current	Іон	Vo = (Vcc - 4 V) *2	0.5	2.0		Α
			Vo = (Vcc - 15 V) *3	2.0			
	Low Level Output Current	Іоь	Vo = (VEE + 2.5 V) *2	0.5	2.0		Α
			Vo = (VEE + 15 V) *3	2.0			
	High Level Output Voltage	Vон	lo = -100 mA ^{*4}	Vcc - 3.5	Vcc - 2.5	Vcc - 1.5	V
	Low Level Output Voltage	Vol	lo = 100 mA		0.1	0.5	V
	High Level Supply Current	Іссн	Vo = open, I _F = 7 to 16 mA		2.0	5.0	mA
	Low Level Supply Current	Iccl	Vo = open, V _F = -2 to +0.8 V		2.0	5.0	mA
	UVLO Threshold	Vuvlo+	Vo > 5 V, IF = 10 mA	11.0	12.3	13.5	V
		Vuvlo-		9.5	10.7	12.0	
	UVLO Hysteresis	UVLO _{HYS}	Vo > 5 V, IF = 10 mA		1.6		V
Coupled	Threshold Input Current (L → H)	lflн	Io = 0 mA, Vo > 5 V		2.0	5.0	mA
	Threshold Input Voltage (H → L)	V _{FHL}	lo = 0 mA, Vo < 5 V	0.8			V



^{*2} Maximum pulse width = 50 μ s, Maximum duty cycle = 0.5%.

^{*3} Maximum pulse width = 10 μ s, Maximum duty cycle = 0.2%

^{*4} VoH is measured with the DC load current in this testing (Maximum pulse width = 2 ms, Maximum duty cycle = 20%).

SWITCHING CHARACTERISTICS (TA = -40 to +100°C, Vcc = 15 to 30 V, IF (ON) = 7 to 16 mA, VF (OFF) = -2 to 0.8 V, VEE = GND, unless otherwise specified)

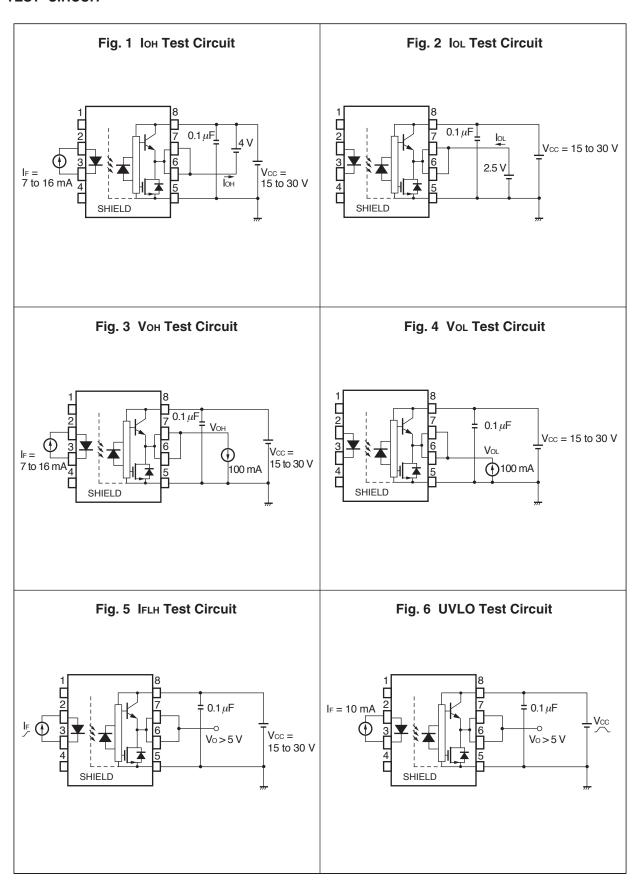
Parameter	Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit
Propagation Delay Time (L → H)	t PLH	$R_g = 10 \ \Omega, \ C_g = 10 \ nF, \ f = 10 \ kHz,$	0.1	0.3	0.5	μS
Propagation Delay Time (H → L)	t PHL	Duty Cycle = 50% ²	0.1	0.3	0.5	μS
Pulse Width Distortion (PWD)	Itphl-tplhI				0.3	μS
Propagation Delay Time (Difference Between Any Two Products)	t РНL— t РLН		-0.35		0.35	μS
Rise Time	tr			0.1		μS
Fall Time	t f			0.1		μS
UVLO (Turn On Delay)	t uvlo on	Vo > 5 V, IF = 10 mA		0.8		μS
UVLO (Turn Off Delay)	tuvlo off	Vo < 5 V, IF = 10 mA		0.6		μS
Common Mode Transient Immunity at High Level Output ^{'3}	СМн	T _A = 25°C, I _F = 10 mA, V _{O (MIN.)} = 26 V, V _{OM} = 1.5k V	15			kV/μs
Common Mode Transient Immunity at Low Level Output ^{*3}	СМ∟	TA = 25°C, IF = 0 mA, Vo (MAX.) = 1 V, VcM = 1.5k V	15			kV/μs

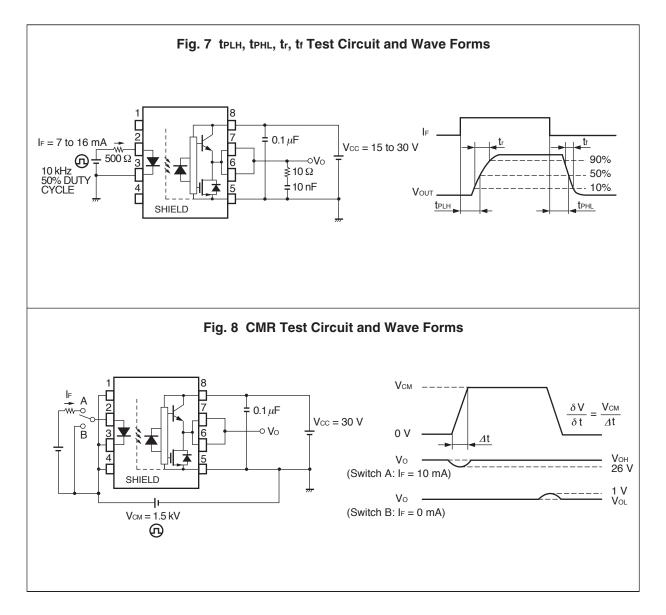
^{*1} Typical values at $T_A = 25^{\circ}C$.

^{*2} This load condition is equivalent to the IGBT load at 1 200 V/75 A.

^{*3} Connect pin 1 and pin 4 to the LED common.

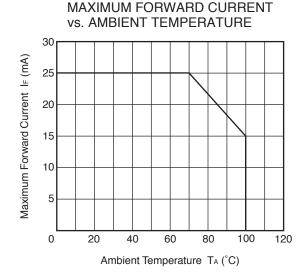
TEST CIRCUIT



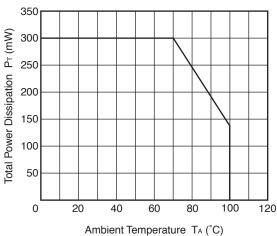


Remark CMR Test: Connect pin 1 and pin 4 to the LED common.

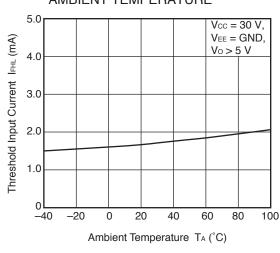
<R> TYPICAL CHARACTERISTICS (TA = 25°C, unless otherwise specified)



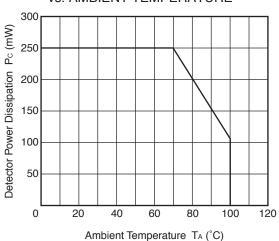




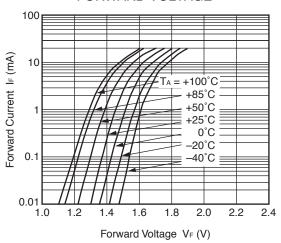
THRESHOLD INPUT CURRENT vs. AMBIENT TEMPERATURE



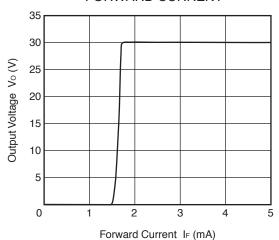
DETECTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



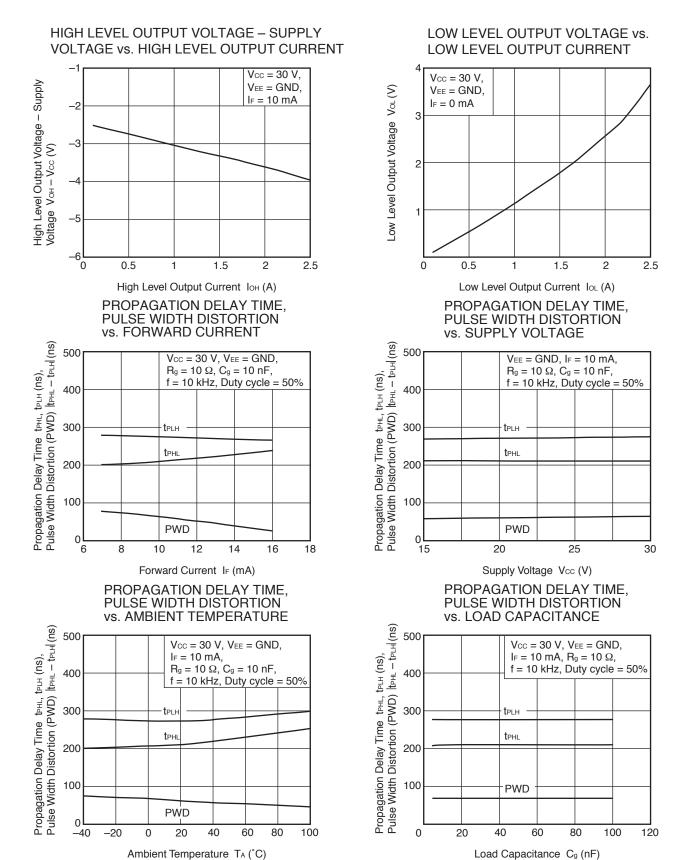
FORWARD CURRENT vs. FORWARD VOLTAGE



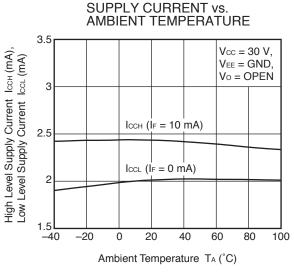
OUTPUT VOLTAGE vs. FORWARD CURRENT



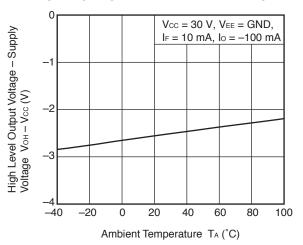
Remark The graphs indicate nominal characteristics.



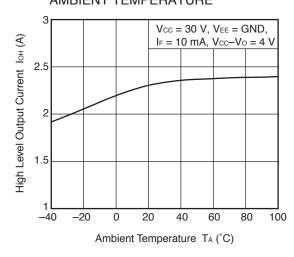
Remark The graphs indicate nominal characteristics.



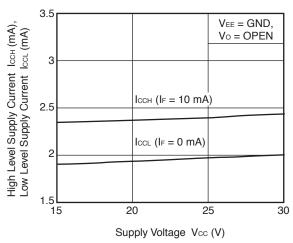
HIGH LEVEL OUTPUT VOLTAGE – SUPPLY VOLTAGE vs. AMBIENT TEMPERATURE



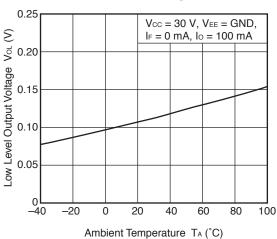
HIGH LEVEL OUTPUT CURRENT vs. AMBIENT TEMPERATURE



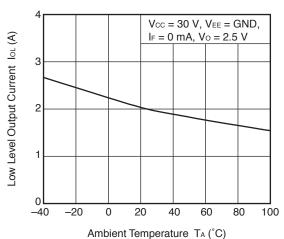
SUPPLY CURRENT vs. AMBIENT TEMPERATURE



LOW LEVEL OUTPUT VOLTAGE vs. AMBIENT TEMPERATURE

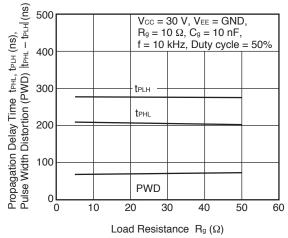


LOW LEVEL OUTPUT CURRENT vs. AMBIENT TEMPERATURE



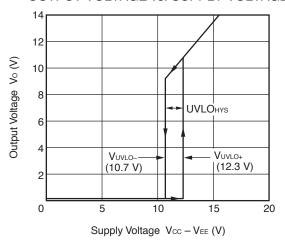
Remark The graphs indicate nominal characteristics.

PROPAGATION DELAY TIME, PULSE WIDTH DISTORTION vs. LOAD RESISTANCE

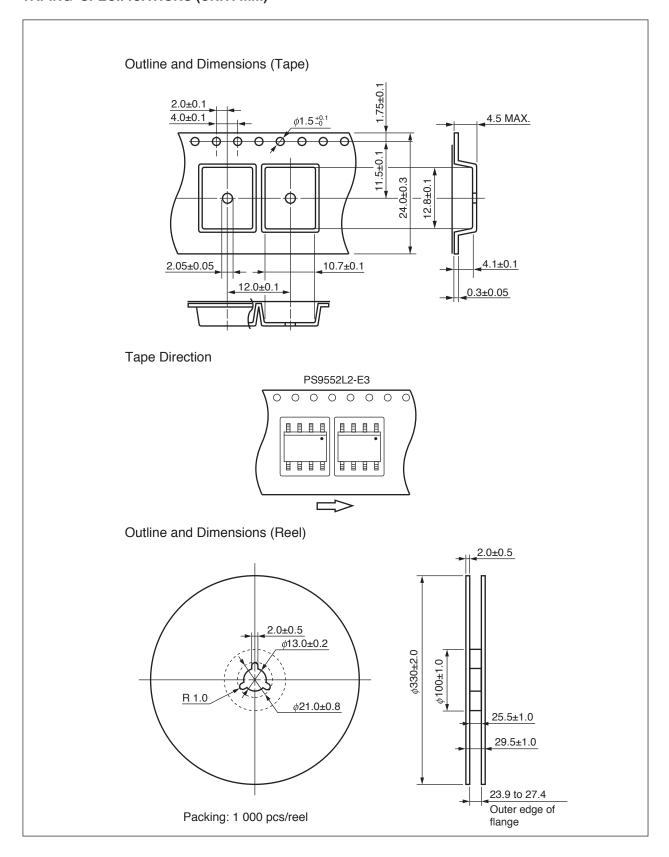


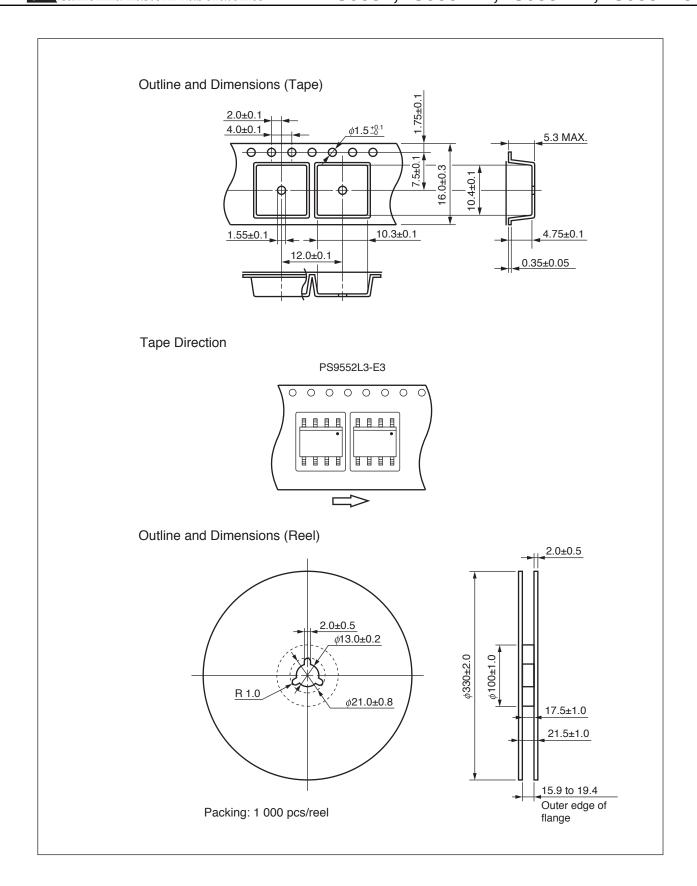
Remark The graphs indicate nominal characteristics.

OUTPUT VOLTAGE vs. SUPPLY VOLTAGE

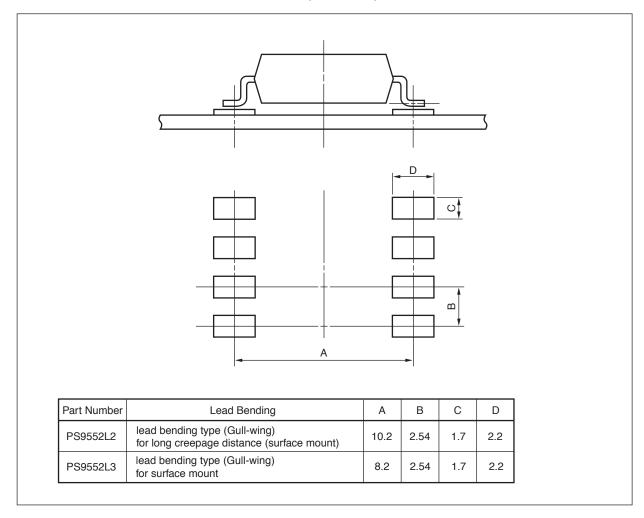


<R> TAPING SPECIFICATIONS (UNIT: mm)





<R>> RECOMMENDED MOUNT PAD DIMENSIONS (UNIT: mm)



NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

Peak reflow temperature
 260°C or below (package surface temperature)

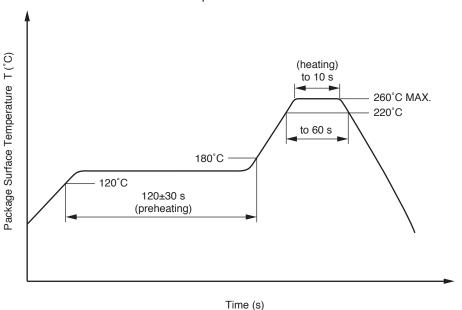
Time of peak reflow temperature
 Time of temperature higher than 220°C
 10 seconds or less
 60 seconds or less

Time to preheat temperature from 120 to 180°C 120±30 s
 Number of reflows Three

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(2) Wave soldering

• Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

• Preheating conditions 120°C or below (package surface temperature)

Number of times
 One (Allowed to be dipped in solder including plastic mold portion.)

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

Peak Temperature (lead part temperature)
 Time (each pins)
 350°C or below
 3 seconds or less

Flux
 Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

- (a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead
- (b) Please be sure that the temperature of the package would not be heated over 100°C

(4) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

<R> 2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

USAGE CAUTIONS

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- <R>> 2. Board designing
 - (1) By-pass capacitor of more than 0.1 μ F is used between Vcc and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
 - (2) In older to avoid malfunctions and characteristics degradation, IGBT collector or emitter traces should not be closed to the LED input.
- <R> 3. Make sure the rise/fall time of the forward current is 0.5 μ s or less.
- 4. In order to avoid malfunctions, make sure the rise/fall slope of the supply voltage is 3 V/ μ s or less.
 - **5.** Avoid storage at a high temperature and high humidity.

<R> SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter		Symbol	Speck	Unit
Application classification (DIN EN 60664-1 VDE0110 for rated line voltages ≤ 300 Vr.m.s. for rated line voltages ≤ 600 Vr.m.s.		IV III		
Climatic test class (DIN EN 60664-1 VDE0110)			55/100/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for t $U_{pr}=1.5 \times U_{IORM}, P_d < 5 \ pC$	Uювм Upr	1 130 1 695	V _{peak} V _{peak}	
Test voltage (partial discharge test, procedure b for a $U_{pr}=1.875\times U_{\text{IORM}},P_{\text{d}}<5\;\text{pC}$	all devices)	Upr	2 119	V_{peak}
Highest permissible overvoltage		Utr	8 000	V _{peak}
Degree of pollution (DIN EN 60664-1 VDE0110 Part	1)		2	
Clearance distance	PS9552, PS9552L3		>7.0	mm
	PS9552L1, PS9552L2		>8.0	
Creepage distance	PS9552, PS9552L3		>7.0	mm
	PS9552L1, PS9552L2		>8.0	
Comparative tracking index (DIN IEC 112/VDE 0303	Part 1)	CTI	175	
Material group (DIN EN 60664-1 VDE0110 Part 1)			III a	
Storage temperature range		Tstg	-55 to +125	°C
Operating temperature range		TA	-40 to +85	°C
Isolation resistance, minimum value VIO = 500 V dc at TA = 25°C VIO = 500 V dc at TA MAX. at least 100°C	Ris MIN. Ris MIN.	10 ¹² 10 ¹¹	Ω Ω	
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current IF, Psi = 0) Power (output or total power dissipation)		Tsi Isi Psi	175 400 700	°C mA mW
Isolation resistance V _{IO} = 500 V dc at T _A = Tsi		Ris MIN.	10°	Ω

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- "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots.
- "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support).
- "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

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(Note)

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- (2) "NEC Electronics products" means any product developed or manufactured by or for NEC Electronics (as defined above).

M8E 02.11-1

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 - Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.



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Facsimile: (408) 988-0279

Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration in CEL	on contained devices	
Lead (Pb)	< 1000 PPM	< 1000 PPM -A Not Detected		
Mercury	< 1000 PPM	Not Detected		
Cadmium	< 100 PPM	Not Detected		
Hexavalent Chromium	< 1000 PPM	Not Detected		
PBB	< 1000 PPM	Not Detected		
PBDE	< 1000 PPM	Not Detected		

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

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